HD151TS301RP

Clock Generator for Printer

HITACHI

ADE-205-603G (Z)

Rev. 7
Oct. 2002

Description

The HD151TS301RP is a high-performance clock generator. It is specifically designed for printer.

Features

- Supports 20 MHz to 50 MHz operation. (Designed for 24 MHz and 48 MHz)
- 1 copy of clock out with spread spectrum modulation @3.3 V
- 1 copy of reference clock @3.3 V
- Programmable spread spectrum modulation (–0.5%, –1.0%, –2.0% and –3.0% down spread modulation.)
- SOP-8pin

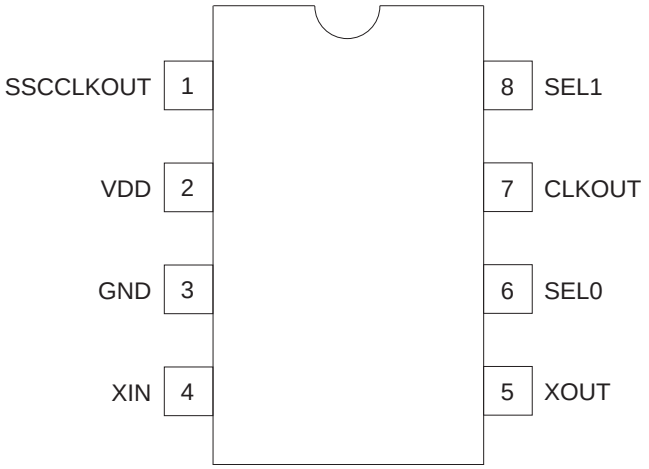
Key Specifications

- Supply voltages : VDD = 3.3 V±0.165 V
- Ta = 0 to 70°C operating range
- Clock output duty cycle = 50±5%
- Ordering Information

Part Name	Package Type	Package Code	Package Abbreviation	Taping Abbreviation (Quantity)
HD151TS301RPEL	SOP-8 pin (JEDEC)	FP-8DC	RP	EL (2,500 pcs / Reel)

Note: Please consult the sales office for the above package availability.

Pin Arrangement



(Top view)

SSC Function Table

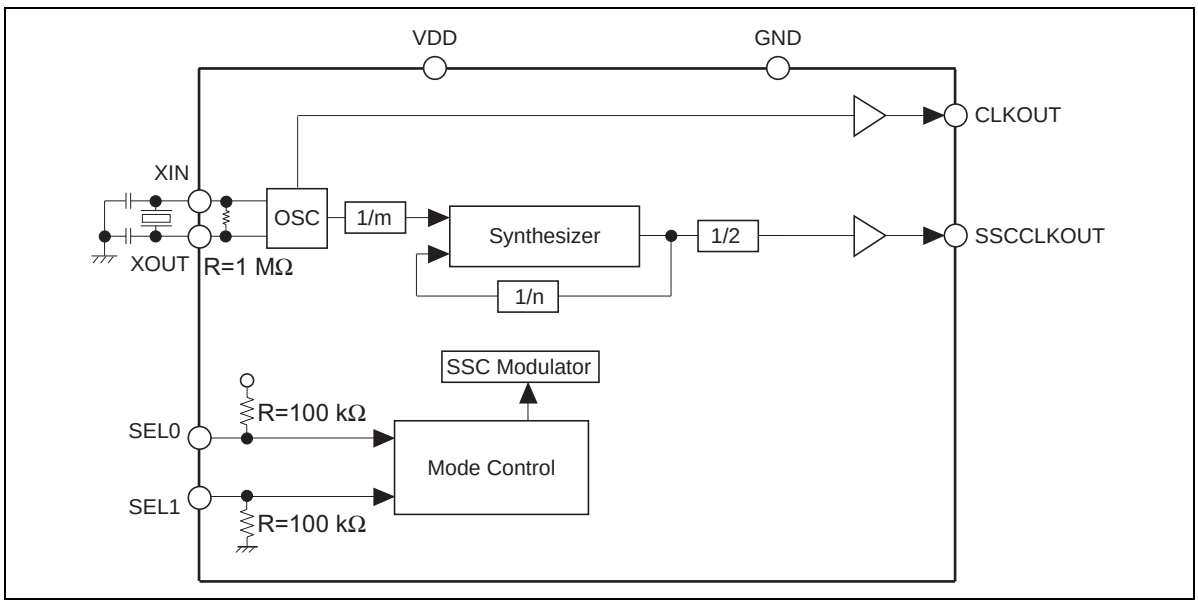
SEL1 :0	Spread Percentage
0 0	–1.0%
0 1	–3.0%
1 0	–2.0%
1 1	–0.5%

Note: –3.0% spread percentage is selected @ default.

Pin Descriptions

Pin name	No.	Type	Description
GND	3	Ground	GND pins
VDD	2	Power	Power supplies pins. Nominal 3.3 V.
CLKOUT	7	Output	Normal 3.3 V reference clock output.
SSCCLKOUT	1	Output	Spread spectrum modulated clock output.
XIN	4	Input	Oscillator input.
XOUT	5	Output	Oscillator output.
SEL0	6	Input	SSC mode select pin. LVCMOS level input. Internal pull–up resistors (typically 100 kΩ).
SEL1	8	Input	SSC mode select pin. LVCMOS level input. Internal pull–down resistors (typically 100 kΩ).

Block Diagram



Absolute Maximum Ratings

Item	Symbol	Ratings	Unit	Conditions
Supply voltage	VDD	–0.5 to 4.6	V	
Input voltage	V_I	–0.5 to 4.6	V	
Output voltage [*1]	V_O	–0.5 to VDD+0.5	V	
Input clamp current	I_{IK}	–50	mA	$V_I < 0$
Output clamp current	I_{OK}	–50	mA	$V_O < 0$
Continuous output current	I_O	±50	mA	V_O = 0 to VDD
Maximum power dissipation at Ta = 55°C (in still air)		0.7	W	
Storage temperature	T_{stg}	–65 to +150	°C	

Notes: Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute maximum rated conditions for extended periods may affect device reliability.

1. The input and output negative voltage ratings may be exceeded if the input and output clamp current ratings are observed.

Recommended Operating Conditions

Item	Symbol	Min	Typ	Max	Unit	Conditions
Supply voltage	VDD	3.135	3.3	3.465	V	
DC input signal voltage		–0.3	—	VDD+0.3	V	
High level input voltage	V_{IH}	2.0	—	VDD+0.3	V	
Low level input voltage	V_{IL}	–0.3	—	0.8	V	
Operating temperature	T_a	0	—	70	°C	
Input clock duty cycle		45	50	55	%	

DC Electrical Characteristics

Ta = 0 to 70°C, VDD = 3.3 V±5%

Item	Symbol	Min	Typ	Max	Unit	Test Conditions
Input low voltage	V_{IL}	—	—	0.8	V	
Input high voltage	V_{IH}	2.0	—	—	V	
Input current	I_I	—	—	±10	µA	V_I = 0 V or 3.465 V, VDD = 3.465 V, XIN
		—	—	±100		V_I = 0 V or 3.465 V, VDD = 3.465 V, SEL0, SEL1
Input slew rate	SR	1	—	4	V / ns	20% – 80%
Input capacitance	C_I	—	—	4	pF	SEL0, SEL1
Operating current		—	11	—	mA	XIN = 24 MHz, C_L = 0 pF, VDD = 3.3 V
		—	22	—		XIN = 48 MHz, C_L = 0 pF, VDD = 3.3 V

DC Electrical Characteristics / Clock Output & SSC Clock Output

Ta = 0 to 70°C, VDD = 3.3 V±5%

Item	Symbol	Min	Typ	Max	Unit	Test Conditions
Output voltage	V_{OH}	3.1	—	—	V	I_{OH} = –1 mA, VDD = 3.3 V
	V_{OL}	—	—	50	mV	I_{OL} = 1 mA, VDD = 3.3 V
Output current	I_{OH}	–55	–85	–125	mA	V_{OH} = 1.5 V
	I_{OL}	55	75	105		V_{OL} = 1.5 V

AC Electrical Characteristics / Clock Output & SSC Clock Output

Ta = 25°C, VDD = 3.3 V, C_L = 30 pF

Item	Symbol	Min	Typ	Max	Unit	Test Conditions	Notes
Cycle to cycle jitter [*1, 2]	t_{CCS}	—	—	| 500 |	ps	@24 MHz	SSCCLKOUT SSC = –0.5%
		—	—	| 500 |		@48 MHz	SEL1:0 = 1 1 Figure 1
		—	—	| 500 |		@24 MHz	SSCCLKOUT SSC = –3.0%
		—	—	| 500 |		@48 MHz	SEL1:0 = 0 1 Figure 1
		—	—	| 500 |		@24, 48 MHz	CLKOUT Figure 1
Output frequency [*1, 2]		23.6	—	24.3	MHz	@24 MHz	SSCCLKOUT SSC = –0.5%
		46.6	—	49.2		@48 MHz	SEL1:0 = 1 1
		23.0	—	24.3		@24 MHz	SSCCLKOUT SSC = –3.0%
		45.5	—	49.2		@48 MHz	SEL1:0 = 0 1
		23.7	—	24.3		@24 MHz	CLKOUT
		46.8	—	49.2		@48 MHz	
Slew rate [*1]	t_{SL}	1.0	—	—	V/ns	@48 MHz	0.4 V to 2.4 V
Clock duty cycle [*1]		45	50	55	%		
Output impedance [*1]		—	30	—	Ω		
Spread spectrum modulation frequency [*1]		—	33	—	KHz	@48 MHz	
Input clock frequency		20	—	50	MHz		
Stabilization time [*1,3]	t_{STAB}	—	—	2	ms		

Notes: 1. Parameters are target of design. Not 100% tested in production.
2. Cycle to cycle jitter and output frequency are included spread spectrum modulation.
3. Stabilization time is the time required for the integrated circuit to obtain phase lock of its input signal after power up.

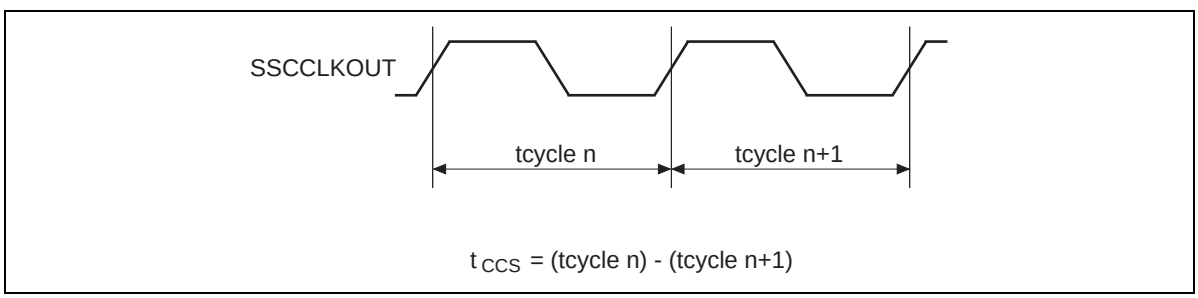


Figure 1 Cycle to cycle jitter (SSCCLKOUT)

Application Information

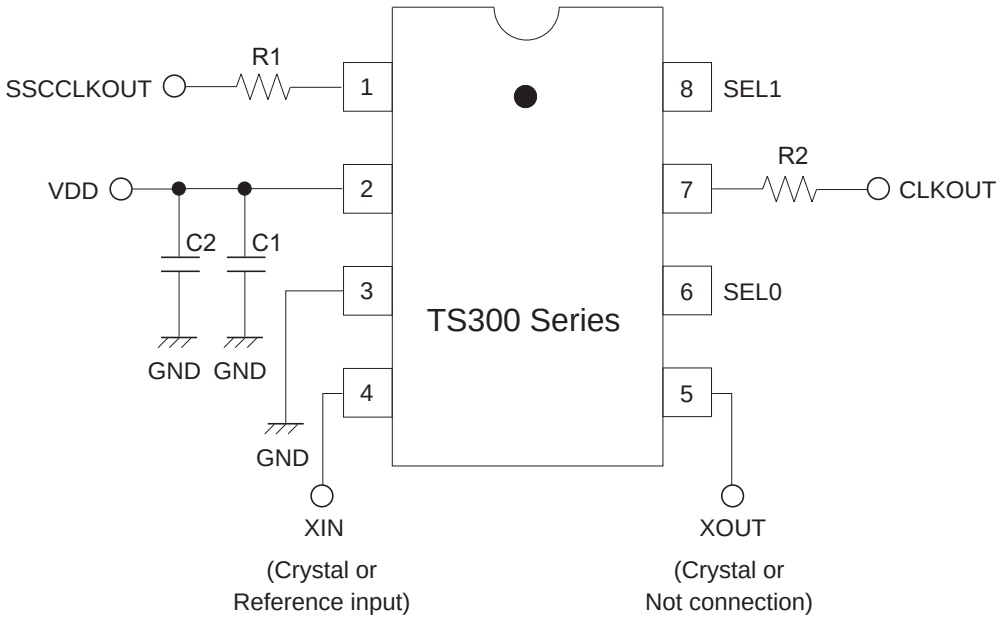
1. Recommended Circuit Configuration

The power supply circuit of the optimal performance on the application of a system should refer to Fig. 2.

VDD decoupling is important to both reduce Jitter and EMI radiation.

The C1 decoupling capacitor should be placed as close to the VDD pin as possible, otherwise the increased trace inductance will negate its decoupling capability.

The C2 decoupling capacitor shown should be a tantalum type.



Notes: C1 = High frequency supply decoupling capacitor.
(0.1 μF recommended)
C2 = Low frequency supply decoupling capacitor.
(22 μF tantalum type recommended)
R1, R2 = Match value to line impedance.
(22 Ω Reference value)

Figure 2 Recommended circuit configuration

2. Example Board Layout Configuration

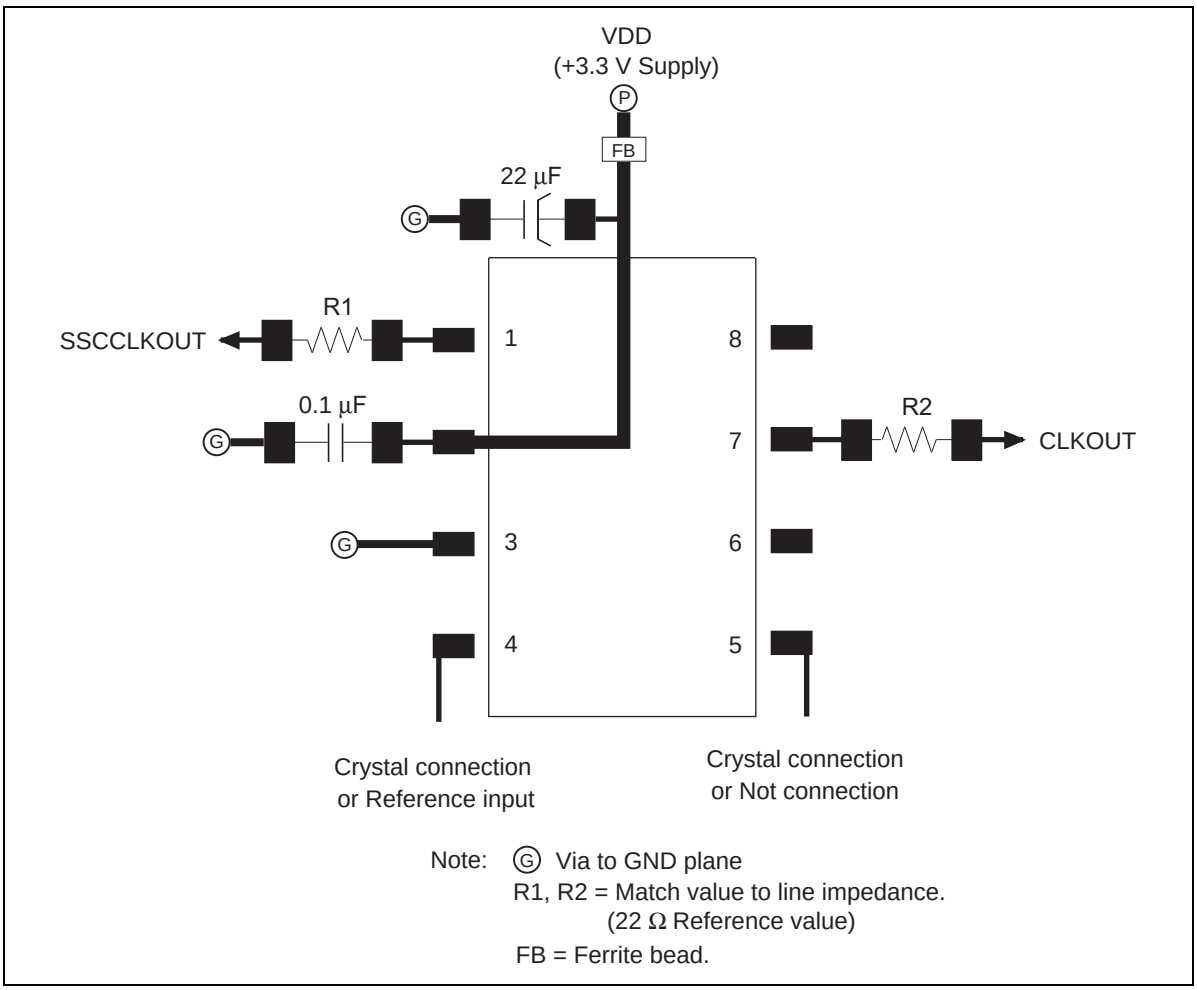


Figure 3 Example Board Layout

3. Example of TS300 EMI Solution IC's Application

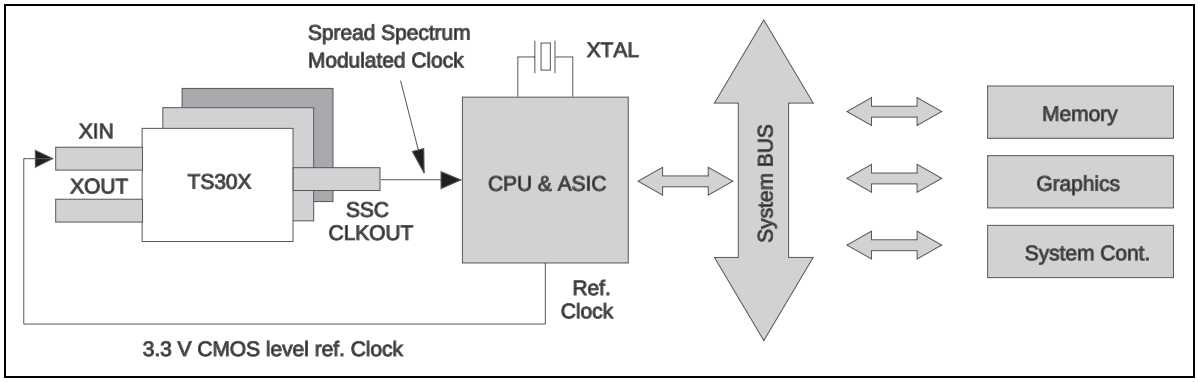


Fig 4 Ref. Clock Input Example

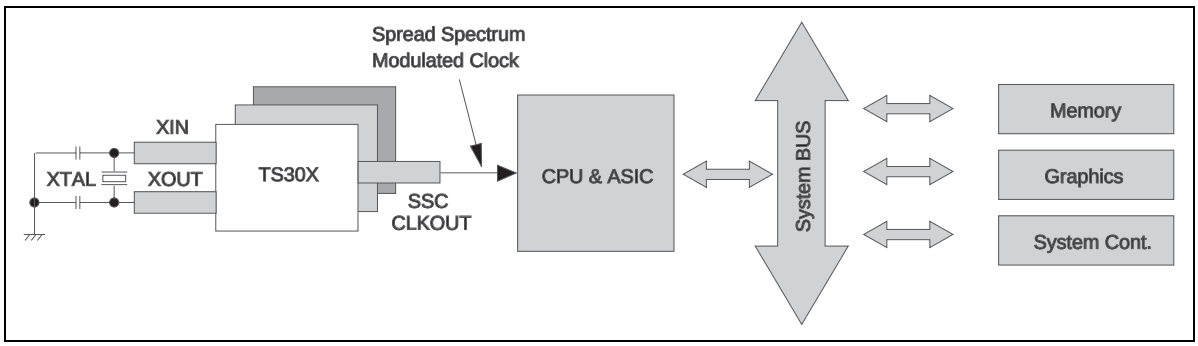
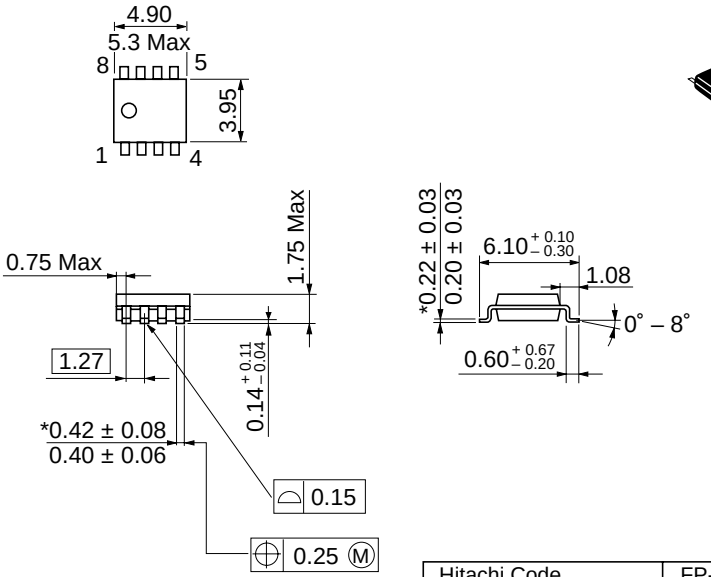


Fig 5 XTAL Ref. Clock Input Example

Package Dimensions

As of July, 2002

Unit: mm



*Dimension including the plating thickness
Base material dimension

Hitachi Code	FP-8DC
JEDEC	Conforms
JEITA	—
Mass (reference value)	0.085 g

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